

DESCRIPTION

The SP6086H is a low-drop diode emulator IC. By combining with an external switch, it replaces Schottky diodes in high-efficiency flyback converters.

The SP6086H generates its own supply voltage and does not need auxiliary winding for either high-side or low-side applications. Programmable ringing detection circuitry prevents the SP6086H from false turning on at $V_{\rm DS}$ oscillations during discontinuous conduction mode (DCM) and quasi-resonant (QR) operation. It has a timing pin to allow SP6086H to turn on at a selected load.

SP6086H is available in space saving SOT-23-6L package.

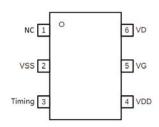
APPLICATIONS

- Industrial Power Systems
- Distributed Power Systems
- Battery Powered Systems
- Flyback Converters
- USB PD Quick Chargers

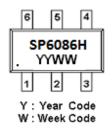
FEATURES

- Does not need auxiliary winding for either high-side or low-side applications
- Fast turn-on and turn-off delay
- Ringing detection prevents false turn-on during DCM and QR operations
- Less than 100mW standby power
- Up to 300KHz
- <400uA quiescent current at light load mode
- Supports CCM, DCM and QR operation
- Support both high-side and low-side rectification
- Available in space saving SOT-23-6L package

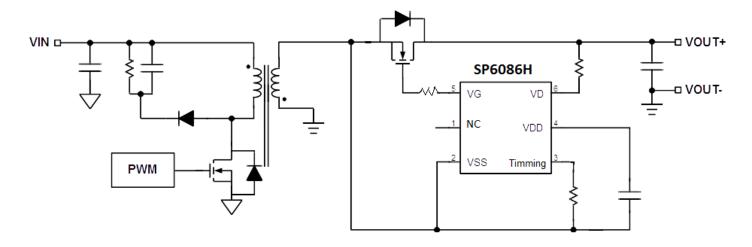
PIN CONFIGURATION (SOT-23-6L)



PART MARKING



TYPICAL APPLICATION CIRCUIT



PIN DESCRIPTION

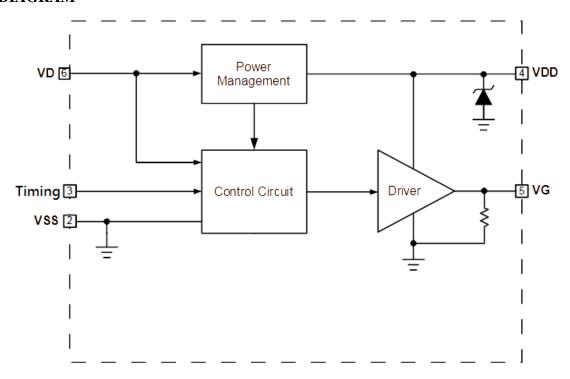
Pin No.	Pin Name	Description	
1	NC		
2	VSS	Ground, also used as reference for VD	
3	Timing	Discontinuous current filter timing adjustment by a resistor	
4	VDD	Linear regulator output. Supply voltage for internal circuits	
5	VG	Gate driver output	
6	VD	External FET drain voltage sensing and input of linear regulator	

ORDERING INFORMATION

Part Number	Package	Part Marking
SP6086HS26RGB	SOT-23-6L	SP6086H

* SP6086HS26RGB : Tape Reel ; Pb – Free ; Halogen – Free

BLOCK DIAGRAM



The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Parameter	Value	Unit	
Vdd	VDD, VG and SL pins voltages to VSS	-0.3 ~ 8.0	V	
VD	VD pin voltage to VSS	- 0.7 ∼ 200	V	
P _D	Power Dissipation @ TA=85°C (*)	0.3	W	
TJ	Junction temperature	- 40 ∼ 150	°C	
T _{STG}	Storage temperature	- 40 ∼ 150	°C	
TLEAD	Lead soldering temperature for 5 sec	260	°C	

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit		
Rөja	Thermal Resistance Junction –to Ambient (*1)	220	°C/W		
Rөjc	Thermal Resistance Junction –to Case (*2)	110	°C/W		

^(*1) θJA is measured in natural convection (still air) at TA = 25°C with the component mounted on a low effective thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

^(*2) The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions



ELECTRICAL CHARACTERISTICS

(T_A=25°C, V_{DD}=5.5V, unless otherwise specified)

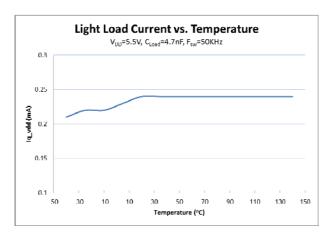
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Supply S	ection					
UVLO	VDD UVLO rising		4.5	4.9	5.3	V
	VDD UVLO Hysteresis			1.2		V
	VDD clamp voltage	$I_{DD} = 10 \text{mA}$		7.5		V
т	VDD charging comment	$V_D = 20V, V_{DD} = 0V$		20		mA
I_{VD}	VDD charging current	$V_D = 20V$, $R_{VDD} = 1K\Omega$		7		mA
	VDD regulation voltage	$V_D = 20V$	6	6.3	6.5	V
I_{CC}	Operating current	C_{LOAD} =4.7nF, F_{SW} =50kHz		5		mA
	Shutdown current	$V_{DD}=UVLO-0.5V$			140	uA
I _{STANDBY}	Light-load mode current	$R_{timing} = 100 k\Omega$		250	400	uA
Control (Circuitry Section					
V_{LL-DS}	VSS-VD turn-on threshold			230		mV
V_{fwd}	VSS-VD forward voltage			25		mV
	VSS-VD turn-off threshold			3		mV
T_{Don}	Turn-on delay	C_{LOAD} =5nF, V_{GS} =2V			75	ns
		$C_{LOAD}=10nF, V_{GS}=2V$			100	ns
	Turn-off propagation delay(*)	$V_D = V_{SS}$		15		ns
T_{Doff}	Turn-off total delay	$V_D=V_{SS}, C_{LOAD}=5nF, R_{GATE}=0\Omega, V_{GS}=2V$		30		ns
		$\begin{array}{c} V_{GS}\!\!=\!\!2V \\ V_{D}\!\!=\!\!V_{SS}, C_{LOAD}\!\!=\!\!10\text{nF}, R_{GATE}\!\!=\!\!0\Omega, \\ V_{GS}\!\!=\!\!2V \end{array}$		40		ns
T_{Bon}	Turn-on blanking time			0.7		us
V_{Boff}	Turn-off blanking V _{DS} threshold		1.5		2.5	V
T_{timing}	Falling slope detection timer	R_{timing} =100k Ω , V_D transition from 2V to -0.1V		30		ns
Vtiming	Reference voltage	Rtiming= 100 k Ω ,	0.95	0.985	1.01	V
T _{LL1}	Light-load-enter pulse width	-		0.8		us
T _{LL1-H}	Light-load-enter pulse width hysteresis			0.3		us
T_{LL2}	Light-load-enter pause width			1		ms
T_{LL-DEL}	Light-load-enter delay			6		cycle
	ver Section		1		I	1 0,010
V _{G-L}	Gate output low voltage	I _{LOAD} =1mA			0.1	V
V_{G-H}	Gate output high voltage	-LUAD	6		V.1	V
, O-11	Peak source current(*)			0.5		A
	Peak sink current(*)			3		A
	Pull down impedance			1	1	Ω

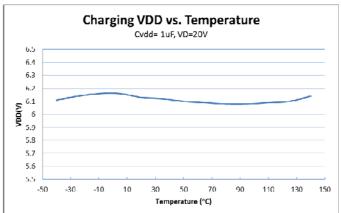
Notes:

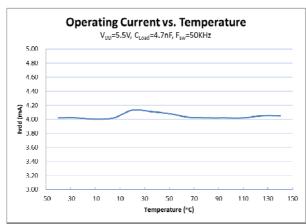
(*)Guaranteed by design and characterization.

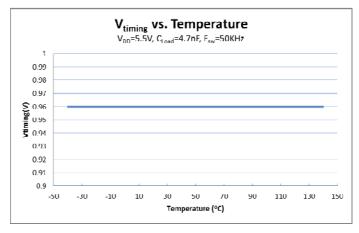


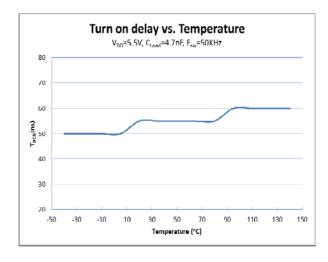
TYPICAL CHARACTERISTICS

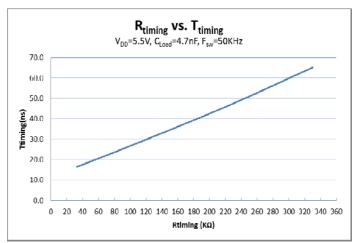














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2023/10/30 Ver 1.0